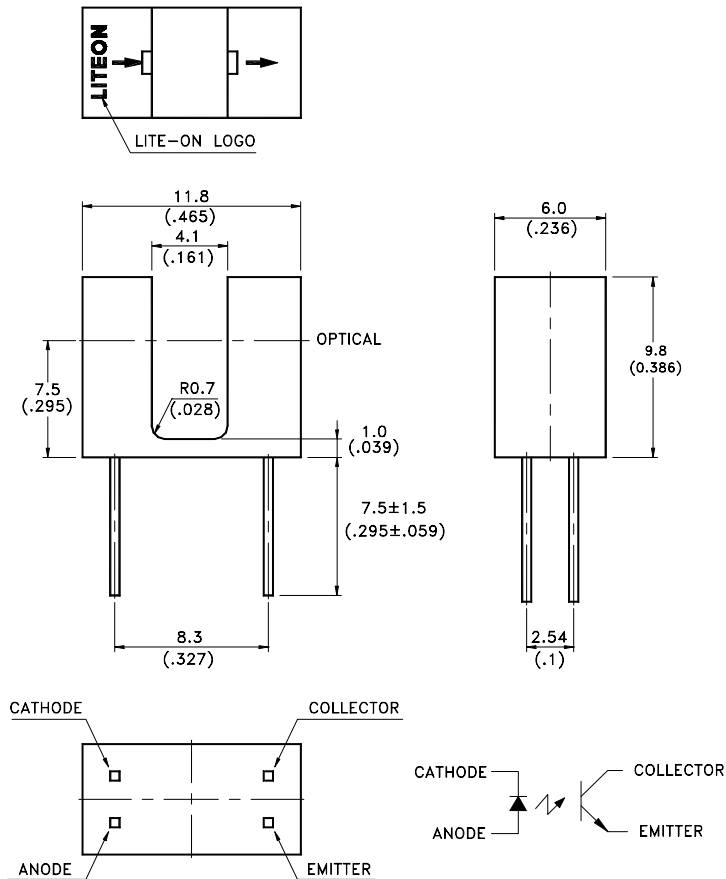


FEATURES

- * NON-CONTACT SWITCHING.
- * FOR DIRECT PC BOARD OR DUAL-IN-LINE SOCKET MOUNTING.
- * FAST SWITCHING SPEED.

PACKAGE DIMENSIONS



NOTES:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25\text{mm}$ (.010") unless otherwise noted.
3. Specification are subject to change without notice.

ABSOLUTE MAXIMUM RATINGS AT TA=25

PARAMETER	MAXIMUM RATING	UNIT
IR Diode Continuous Forward Current	50	mA
IR Diode Reverse Voltage	5	V
Transistor Collector Current	40	mA
Transistor Power Dissipation	100	mW (Note 1)
IR Diode Peak Forward Current (Pulse Wide = 10 μ S, 300 pps)	1	A
Diode Power Dissipation	75	mW (Note 1)
Phototransistor Collector-Emitter Voltage	30	V
Phototransistor Emitter-Collector Voltage	5	V
Operating Temperature Range	-35 to + 65	
Storage Temperature Range	-40 to + 100	
Lead Soldering Temperature [1.6mm(.063") From Case]	260 for 5 Seconds	

Note 1: Derate Linearly 1.33mW/ from 25

ELECTRICAL OPTICAL CHARACTERISTICS AT TA=25

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
INPUT LED						
Forward Voltage	V _F		1.2	1.6	V	I _F = 20mA
Reverse Current	I _R			100	μ A	V _R =5V
OUTPUT PHOTOTRANSISTOR						
Collector-Emitter Breakdown Voltage	V(BR) _{CEO}	30			V	I _C =1mA
Emitter-Collector Breakdown Voltage	V(BR) _{ECO}	5			V	I _E =100 μ A
Collector-Emitter Dark Current	I _{CEO}			100	nA	V _{CE} =10V
COUPLER						
Collector-Emitter Saturation Voltage	V _{CE} (SAT)			0.4	V	I _C =0.25mA I _F =20mA
On State Collector Current	I _C (ON)	1.5			mA	V _{CE} =5V I _F =20mA

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTICS CURVES

(25 Ambient Temperature Unless Otherwise Noted)

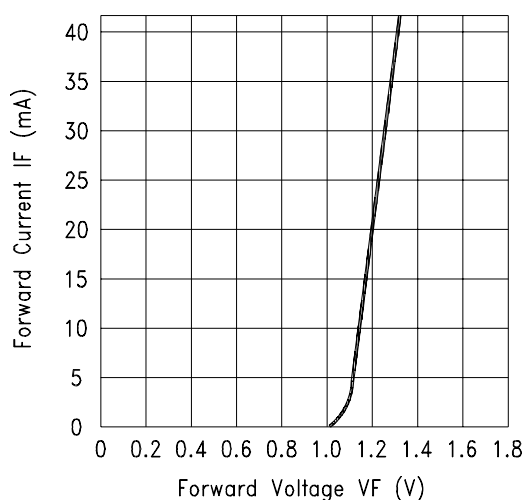


Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE

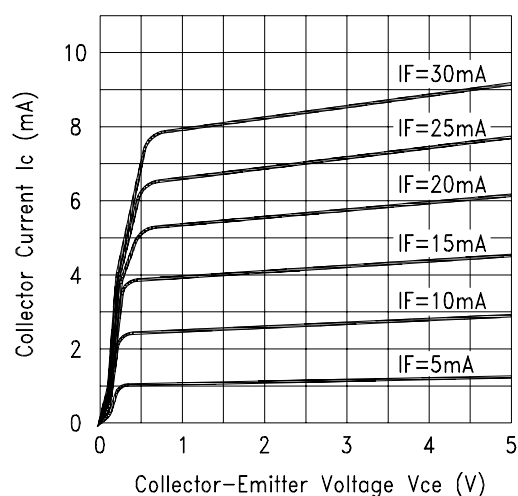


Fig.2 COLLECTOR CURRENT VS. COLLECTOR VOLTAGE

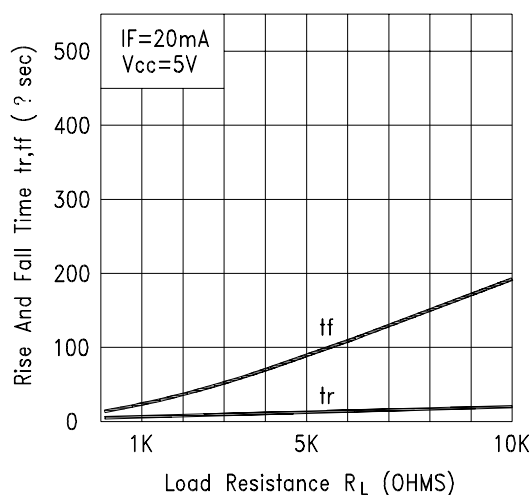


Fig.3 RISE AND FALL TIME VS. LOAD RESISTANCE

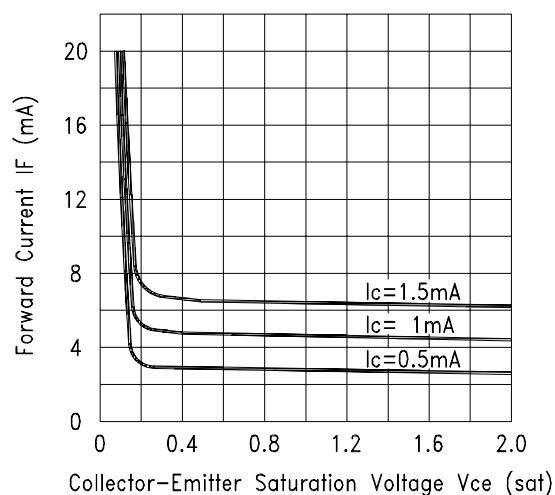


Fig.4 FORWARD CURRENT VS. Collector-Emitter Saturation Voltage